

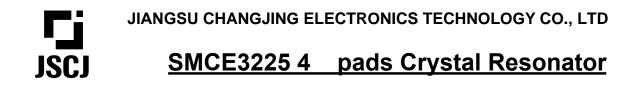
产品规格书

SPECIFICATIONS FOR PRODUCT

| 产品类型 | TYPE | : | SMD3225 |
|------|------|---|-----------------------|
| 产品规格 | SPEC | : | 24MHz/3225/10PF/10PPM |
| 产品型号 | P/N | : | CJ13-240001010B20 |
| 日期 | DATE | : | 2018/12/05 |

| 核准及签名 | | | 部バ |
|------------|------------|------------|---------|
| R&D APPR. | SIGNATURED | | DEPT. |
| 拟制 | 审核 批准 | | 频率器件事业部 |
| ISSUE | CHECK | APPROVAL | |
| 王嘉诚 | 许秋菊 | 杨立新 | |
| 2018/12/05 | 2018/12/05 | 2018/12/05 | |

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CJ13-240001010B20

- 1. Scope:
- 1.1 This specification applies to the RoHS/SONY compliance quartz crystal unit with a frequency of 24MHz which will be used in crystal oscillator applications.
- 2. Construction:
- 2.1 Type of Quartz Resonator: SMCE3225 4pads

3. Electrical Characteristics

| 3.1 | Nominal Frequency(f): | 24MHz |
|--------------------|--|------------------------|
| 3.2 | Load Capacitance(C _L): | 10pF |
| 3.3 | Frequency Tolerance(△f/f): | ±10ppm |
| 3.4 | Frequency Temperature Stability: | ±20ppm |
| 3.5 | Resonance Resistance(ohm): | 60ohms Max |
| 3.6 | Osc mode: | Fundamental mode |
| | | |
| 3.7 | Shunt Capacitance(C ₀): | <2pF |
| | Shunt Capacitance(C ₀): Drive Level(D _L): | <2pF < 100µW |
| 3.8 | | |
| 3.8 3.9 | Drive Level(D _L): | - < 100μW |
| 3.8 3.9 3.10 | Drive Level(D _L): Operating Temperature Range(T _{OPR}): | < 100µW -40 to + 85 |

4. Reliability Specifications

This is the quality control and quality assurance and reliability tests performance data for the RoHS/

SONYcompliance 24MHz SMCE3225 4pads crystal resonators

related to the specification and approval sheet provided by JSCJ .

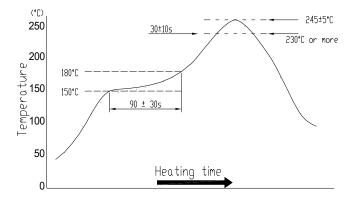
Standard test condition (TEMP.: 20±5°C. Relative humidity: 65±20%)

For any discrepancy in GO/NG, test will be done at TEMP.25±2°C, R.H. 65±5%.

| NO. | PROCESS | SPECIFICATION | TEST METHOD |
|------|---|--|---|
| 4.1 | Temperature Cycle(GB/T 2423.22-2002, Method Nb) | Frequency change after test ≤± 5ppm.Resonance resistance change after test ≤10ohms. | 10 cycles from -55°C to 125°C. Measurement taken after DUT being left at room temperature for 24±2 hours. |
| 4.2 | Low Temperature Storage (GB/T 2423.1-2001, Method Aa) | Frequency change after test ≤± 5ppm.Resonance resistance change after test ≤10ohms. | Spending 72 hrs at -55°C±3°C constant temperature. Measurement taken after DUT being left at room temperature for 24±2 hours. |
| 4.3 | High Temperature Storage (GB/T 2423.2-2001, Method Ba) | Frequency change after test ≤± 5ppm.Resonance resistance change after test ≤10ohms. | Spending 72 hrs at 125°C±3°C constant temperature. Measurement taken after DUT being left at room temperature for 24±2 hours. |
| 4.4 | Humidity (GB/T 2423.3- 2006, Method Cab) | Frequency change after test ≤± 5ppm.Resonance resistance change after test ≤10ohms. | Spending 96 hrs at 40 °C \pm 3 °C, with 93 %R.H, Then keep the DUT in dry oven at 40 \pm 5 °C for 24 hour. Measurement taken after DUT being left at room temperature for 1 to 2 hours. |
| 4.5 | Vibration (GB/T 2423.10- 1995, Method Fc) | Frequency change after test ≤± 5ppm.Resonance resistance change after test ≤10ohms. | Apply 0.75mm vibration at sweep frequency $10\sim$ 500 Hz, 10 cycles in each direction of 3 axis. Measurement taken after 1 hour. |
| 4.6 | Shock (GB/T 2423.5-1995, Method Ea) | Frequency change after test ≤± 5ppm.Resonance resistance change after test ≤10ohms.and exhibit no visible damage. | Peak 1000m/s2, normal width 6ms half sine wave form, 3.7m/s, 3 perpendicular axis of samples, 3 cycles / direction, total 18 cycles. Measurement taken after 1 hour. |
| 4.7 | Drop (GB/T 2423.8-1995, Method Ed) | Frequency change after test ≤± 5ppm.Resonance resistance change after test ≤10ohms.and exhibit no visible damage. | Free drop to the steel plate with thickness of 3 mm from 1.00 m heights for 3 times. |
| 4.8 | Solderability (IEC60068-2- 58,Test Td:) | Terminals shall be covered more then 95% with solder. | Passed through the re-flow oven under the following condition. Preheat 150 to 180° C for 60 to 120sec, and soldering time for $20s \pm 5s$ at 235° C, peak soldering time for $10s \pm 1s$ betweein 240 and 250°C. There is no need to do functional test. 8-12X magnifier. |
| 4.9 | Terminal Strength (JIS-C- 6429 Method 1 & 2) | No visible damage | Mount on a glass-epoxy board (100x50x1.6mm), then bend to 2mm displacement (velocity 1mm/sec) and keep for 5 seconds. or pulling force 1.8kg for at least 60 seconds. |
| | | | |
| 4.10 | Resistance to Soldering Heat (IEC60068-2-58,Test Td: Table 4) | Frequency change after test ≤± 5ppm.Resonance resistance change after test ≤10ohms. | Passed through the re-flow oven under the following condition. Preheat 150 to 180°C for 60 to 120sec, and sodering time for 60s max at 235°C, peak soldering time for 20s max at 265°C max. Measurement taken after DUT being left at room temperature for at least 2 hours. |
| | | | |
| 4.11 | OTHERS | | |

5. Recommended Reflow soldering condition (SMD) Solder profile

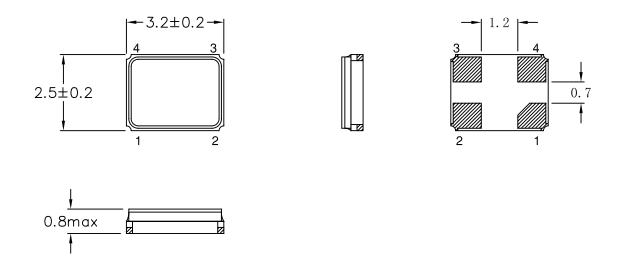
Peak: 245±5°C Soldering zone: 230°C or more, 30±10s. Pre-heating zone 1: 150 \sim 180°C, 90±30s



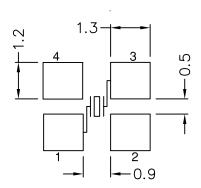
Temperature profile for reflow soldering

6. Soldering iron method

Bit temperature: 350 ± 10 °C Application time of soldering iron:3+1 s. For other procedures, refer to IEC 60068-2-20.

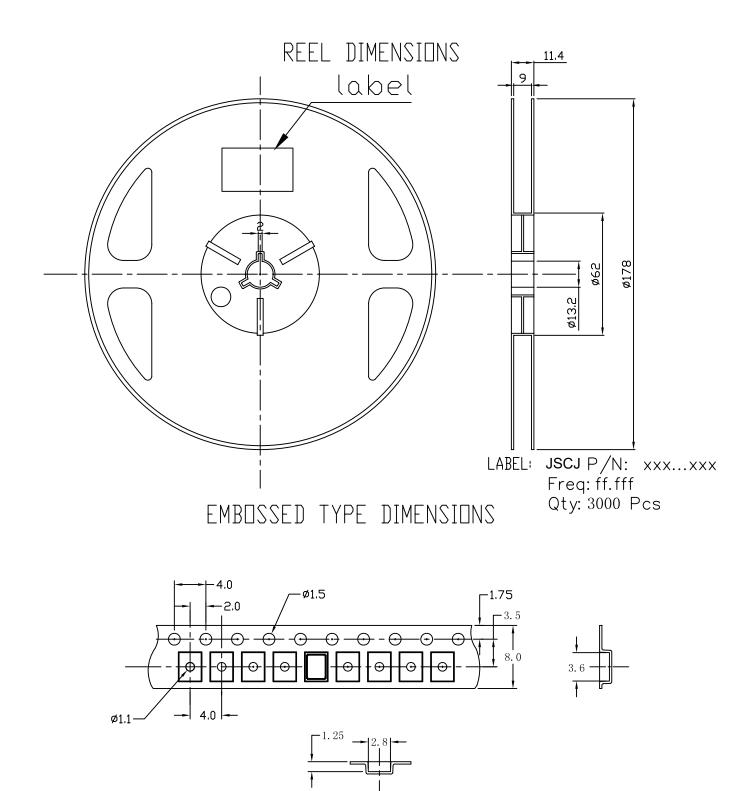


Suggested Pad Layout



NOTICE

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